NSN 5962-01-430-2308

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-430-2308

Body Length:

Between 0.816 inches and 0.838 inches

Body Width:

Between 0.430 inches and 0.445 inches

Body Height:

Between 0.088 inches and 0.120 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

5895-01-412-4427

Features Provided:

Monolithic and electrostatic sensitive and low power and burn in, mil-std-883, class b

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, memory, digital, cmos, 128k x 8 static random access memory (sram) low power

Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

Time Rating Per Chacteristic:

35.00 nanoseconds input to output access

Memory Device Type:

Ram

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

32 j-hook

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

NSN 5962-01-430-2308

Memory Microcircuit - Page 2 of 2

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